NSN 5962-01-424-1771

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
E-3 esm grp b
Features Provided:
Programmed
Inclosure Configuration:
Dual-in-line
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds input to output access
Memory Device Type:
Memory Device Type: Pal
Pal
Pal Terminal Type And Quantity:
Pal Terminal Type And Quantity: 20 printed circuit
Pal Terminal Type And Quantity: 20 printed circuit Shelf Life:
Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a
Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a
Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure:
Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization:
Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli